

SK22A SCHOTTKY RECTIFIER

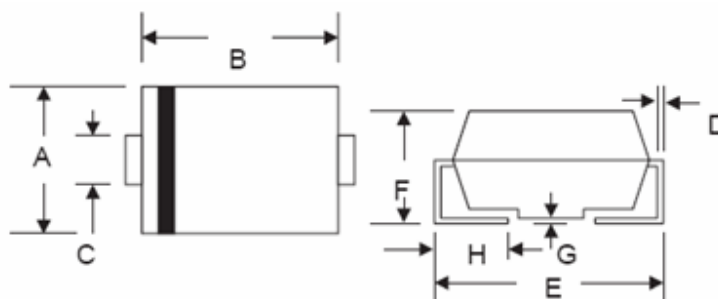
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 125°C TJ operation Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

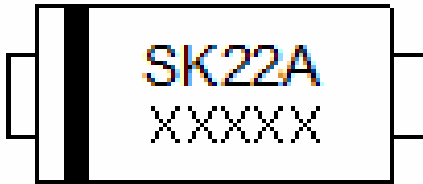
Mechanical Dimensions (In mm / Inches)



SMA/DO-214AC				
Dim	Min	Max	Min	Max
A	2.50	2.90	0.098	0.114
B	4.00	4.60	0.157	0.181
C	1.40	1.60	0.055	0.063
D	0.152	0.305	0.006	0.012
E	4.80	5.28	0.189	0.208
F	2.00	2.44	0.079	0.096
G	0.051	0.203	0.002	0.008
H	0.76	1.52	0.030	0.060
		In mm	In inch	

SMA

Marking Diagram:



Where XXXXX is YYWWL

SK = Device Type
2 = Forward Current (2A)
2 = Reverse Voltage (20V)
A = Package type
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK22A	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	20	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @TC =105 °C rectangular wave form(L=0.375")	2.0	A
Max. Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine pulse	50	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 2A, Pulse, $T_J = 25^{\circ}\text{C}$	0.55	V
Max. Reverse Current	I_{R1}	@ $V_R = \text{rated VR}$ $T_J = 25^{\circ}\text{C}$	1.0	mA
	I_{R2}	@ $V_R = \text{rated VR}$ $T_J = 100^{\circ}\text{C}$	20	mA
Typical Junction Capacitance	C_j	@ $V_R = 4.0\text{ V}$, $T_C = 25^{\circ}\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	250	pF

* Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +125	$^{\circ}\text{C}$
Max. Storage Temperature	T_{stg}	-	-55 to +150	$^{\circ}\text{C}$
Maximum Thermal Resistance Junction to Case	$R_{\theta\text{Jc}}$	DC operation	8	$^{\circ}\text{C/W}$
Approximate Weight	wt	-	0.11	g
Case Style	SMA			

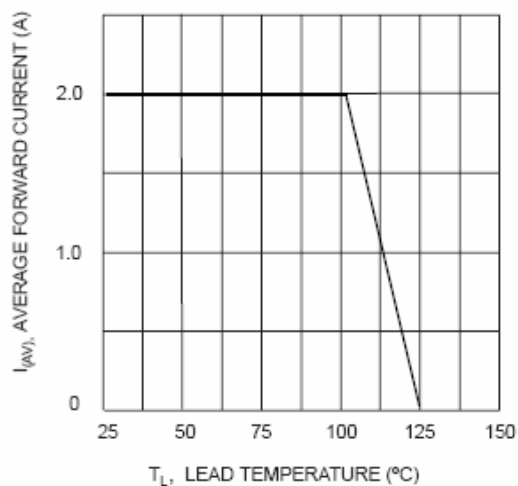


Fig. 1 Forward Current Derating Curve

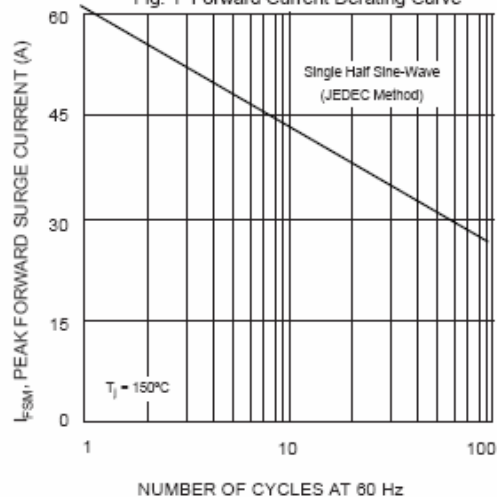


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

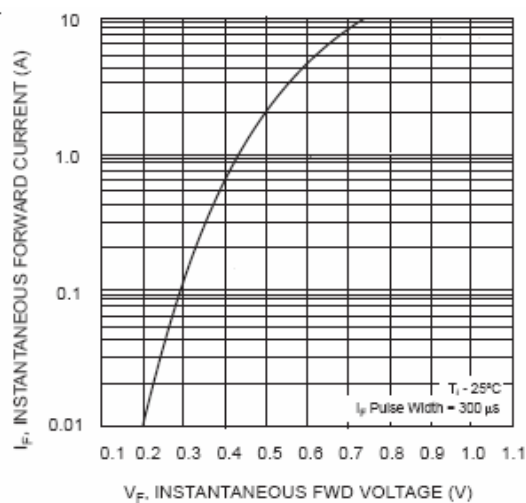


Fig. 2 Typ. Forward Characteristics

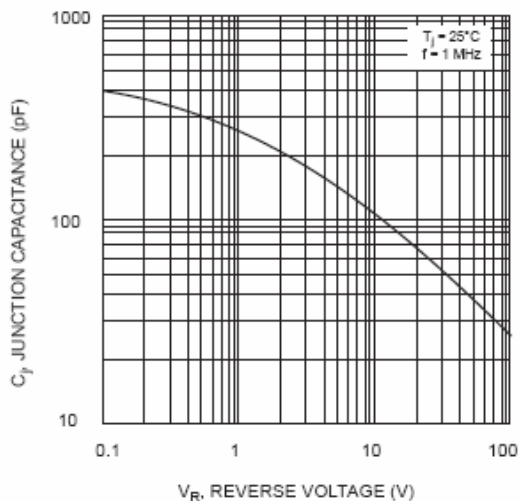


Fig. 4 Typical Junction Capacitance

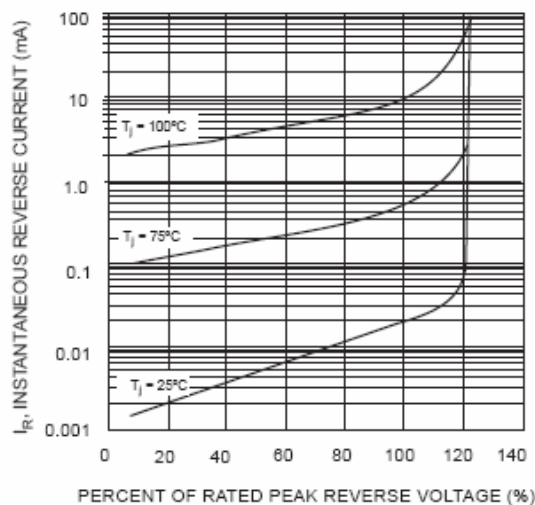


Fig. 5 Typical Reverse Characteristics

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